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[54] **SEMICONDUCTOR POLYMER**

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[58] **Field of Search** 252/500, 519.34; 524/609, 612

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[57] **ABSTRACT**

The invention relates to a semiconducting polymer and a method of preparing a semiconducting polymer. The polymer in accordance with the invention has the repeating unit (—A—NH—B—S—), wherein A and B are conjugated groups. The polymer proves to be readily soluble already in customary organic solvents, without the groups A and B having been provided with saturated substituents, and, after doping, has an electric conductivity of approximately 1 S/cm. The method yields semiconducting polymers in accordance with the invention, which have a high molecular weight and few topological defects.

11 Claims, 1 Drawing Sheet